

Devi Ahilya University, Indore, India Institute of Engineering & Technology				ME – I Year (Spl Digital Communication) Semester- B			
Subject Code & Name	Instructions Hours per Week			Credits			
DCP3G2 Nanodevices & Nanosensors	L	T	P	L	T	P	Total
	3	1	0	3	1	0	4
Duration of Theory Paper: 3 Hours							

Course Objectives: this course will focus on understanding of the basic structure principals of Nano-devices and sensors.

Prerequisite(s): Introduce the quantum mechanical concepts needed to understand the operation

COURSE CONTENTS

Unit-I

QUANTUM DEVICES Quantum Electronic devices – Electrons in mesoscopic structures – Short channel, MOS Transistor – split Gate Transistor – Electron wave transistor – Electron spin transistor – Quantum Dot array – Quantum computer- Bit and Qubit. Carbon Nanotube based logic gates, optical devices. . Connection with quantum dots, quantum wires, and quantum wells

Unit-II

TUNNELING DEVICES Tunneling element – Tunnel Effect and Tunneling Elements-Tunneling Diode – Resonant Tunneling Diode – Three -Terminal Resonate Tunneling Devices-Technology of RTD-Digital circuits design based on RTDs - Basics Logic Circuits – Single Electron Transistor (SET) – Principle – Coulomb Blockade- Performance – Technology- Circuit Design- Logic and Memory Circuits – SET adder as an Example of a Distributed Circuit.

Unit-III

NANOSENSORS I Micro and nano-sensors, Fundamentals of sensors, biosensor, micro fluids, Packaging and characterization of sensors, Method of packaging at zero level, dye level and first level. Sensors for aerospace and defense: Accelerometer, Pressure Sensor, Night Vision System, Nano tweezers, nano-cutting tools, Integration of sensor with actuators and electronic circuitry,

Unit-IV

NANOSENSORS II Sensor for bio-medical applications: Cardiology, Neurology and as diagnostic tool, For other civil applications: metrology, bridges etc. Biosensors. Clinical Diagnostics, generation of biosensors, immobilization, characteristics, applications, conducting Polymer based sensor, DNA Biosensors, optical sensors. Biochips. Metal Insulator Semiconductor devices, molecular electronics, information storage, molecular switching, Schottky devices,

Unit-V

NEMS Inertial sensors – accelerometer – gyroscope - micromechanical pressure sensors – pizoresistive –capacitive - microrobotics – micro channel heat sinks – optical MEMS – visual display – precision optical platform – optical data switching – RF MEMS – MEMS variable capacitors – MEMS switches – Resonators.

BOOKS RECOMMENDED:

- [1]. K. Goser, P. Glosekotter and J. Dienstuhl, “Nanoelectronics and Nanosystems-From Transistors to Molecular Quantum Devices”, Springer, 2004.
- [2]. Herve Rigneault, Jean-Michel Lourtioz, Claude Delalande, Ariel Levenson, “Nanophotonics”, ISTE.
- [3]. W.R. Fahrner, “Nanotechnology and Nanoelectronics – Materials, Devices and Measurement Techniques” Springer, 2006 13

- [4]. Nano Engineering in Science & Technology : An introduction to the world of nano design by Michael Rieth.
- [5]. Tai –Ran Hsu, “MEMS & Microsystems Design and Manufacture”, Tata McGraw-Hill publication, 2001.
- [6]. P. Rai-Choudhury, “MEMS and MOEMS technology and applications”, PHI learning private Ltd, 2009.
- [7]. Mohamed Gad-el-Hak, “The MEMS Handbook”, CRC Press, 2002.